

ZVN4210G

SOT223 N-CHANNEL ENHANCEMENT MODE VERTICAL DMOS FET

Product Summary

BV _{DSS}	R _{DS(on)}	I _D T _A = +25°C
100V	1.5Ω @ V _{GS} = 10V	800mA

Features and Benefits

- Lead-Free Finish; RoHS Compliant (Notes 1 & 2)
- Halogen and Antimony Free. "Green" Device (Note 3)
- For automotive applications requiring specific change control (i.e. parts qualified to AEC-Q100/101/200, PPAP capable, and manufactured in IATF 16949 certified facilities), please <u>contact us</u> or your local Diodes representative. https://www.diodes.com/quality/product-definitions/

Description and Applications

This MOSFET is designed to minimize the on-state resistance and yet maintain superior switching performance, making it ideal for high efficiency power management applications

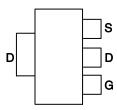
Mechanical Data

- Package: SOT223 (Type DN)
- Package Material: Molded Plastic, UL Flammability Classification Rating 94V-0
- Moisture Sensitivity: Level 1 per J-STD-020
- Terminals: Finish Matte Tin Annealed over Copper Leadframe. Solderable per MIL-STD-202, Method 208 (3)
- Weight: 0.112 grams (Approximate)

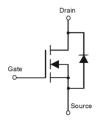
SOT223(Type DN)



Top View



Pin Out - Top View



Equivalent Circuit

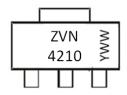
Ordering Information (Note 4)

Part Number	Package	Packing		
Part Number	rackaye	Qty.	Carrier	
ZVN4210GTA	SOT223 (Type DN)	1,000	Tape & Reel	

Notes:

- 1. EU Directive 2002/95/EC (RoHS), 2011/65/EU (RoHS 2) & 2015/863/EU (RoHS 3) compliant. All applicable RoHS exemptions applied.
- 2. See https://www.diodes.com/quality/lead-free/ for more information about Diodes Incorporated's definitions of Halogen- and Antimony-free, "Green" and Lead-free.
- 3. Halogen- and Antimony-free "Green" products are defined as those which contain <900ppm bromine, <900ppm chlorine (<1500ppm total Br + Cl) and <1000ppm antimony compounds.
- 4. For packaging details, go to our website at https://www.diodes.com/design/support/packaging/diodes-packaging/

Marking Information



ZVN4210 = Product Type Marking Code YWW = Date Code Marking Y or \overline{Y} = Year (ex: 1 = 2021) WW or $\overline{W}W$ = Week (01 to 53)

ZVN4210G Document Number DS33366 Rev. 4 - 2 1 of 5



Maximum Ratings (@ T_A = +25°C, unless otherwise specified.)

Characteristic	Symbol	Value	Unit
Drain-Source Voltage	V _{DSS}	100	V
Gate-Source Voltage	V_{GSS}	±20	V
Continuous Drain Current $V_{GS} = 10V$ $T_A = +25^{\circ}C$	I _D	800	mA
Pulsed Drain Current	I _{DM}	6	А

Thermal Characteristics (@ T_A = +25°C, unless otherwise specified.)

Characteristic		Symbol	Value	Unit
Total Power Dissipation	T _A = +25°C	P_{D}	2	W
Operating and Storage Temperature Range		$T_{J_1}T_{STG}$	-55 to +150	°C

Electrical Characteristics (@ T_A = +25°C, unless otherwise specified.)

Characteristic	Symbol	Min	Тур	Max	Unit	Test Condition	
OFF CHARACTERISTICS							
Drain-Source Breakdown Voltage	BV _{DSS}	100	-	_	V	$V_{GS} = 0V$, $I_D = 1mA$	
Zoro Coto Voltago Drain Current		-	-	10	μΑ	$V_{DS} = 100V, V_{GS} = 0V$	
Zero Gate Voltage Drain Current	I _{DSS}	-	-	100	μΑ	V _{DS} =80V, V _{GS} =0V, T=125°C (Note 6)	
Gate-Source Leakage	I _{GSS}	_	-	±100	nA	$V_{GS} = \pm 20V, V_{DS} = 0V$	
ON CHARACTERISTICS							
Gate Threshold Voltage	V _{GS(th)}	0.8	-	2.4	V	$V_{DS} = V_{GS}$, $I_D = 1mA$	
Static Dunin Source On Benintance		_	-	1.5	Ω	$V_{GS} = 10V, I_D = 1.5A$	
Static Drain-Source On-Resistance	R _{DS(on)}	_	-	1.8	Ω	$V_{GS} = 5V, I_D = 0.5A$	
Diada Famusad Valtana (Nata F)	.,	-	0.79	-	V	I _S =0.32A, V _{GS} =0V	
Diode Forward Voltage (Note 5)	V _{SD}	_	0.89	_	٧	I _S =1.0A, V _{GS} =0V	
On-State Drain Current (Note 5)	I _{D(on)}	2.5	-	_	Α	V _{DS} =25V, V _{GS} =10V	
Forward Transconductance (Notes 5, 6)	g fs	250	-	-	mS	V _{DS} =25V,I _D =1.5A	
Reverse Recovery Time (to I _R =10%)	t _{RR}	-	135	-	ns	$I_F = 0.45A, V_{GS} = 0V, I_R = 100mA,$ $V_R = 10V$	
DYNAMIC CHARACTERISTICS (Note 6)							
Input Capacitance	C _{iss}	-	-	100	pF		
Output Capacitance	Coss	-	-	40	pF	$V_{DS} = 25V, V_{GS} = 0V, f = 1MHz$	
Reverse Transfer Capacitance	C _{rss}	-	-	12	pF	1	
Turn-On Delay Time (Note 7)	t _{D(on)}	_	-	4	ns		
Turn-On Rise Time (Note 7)	t _R	-	-	8	ns)/ O5\/ 4.54	
Turn-Off Delay Time (Note 7)	t _{D(off)}	-	-	20	ns	$V_{DD} = 25V, I_{D}=1.5A$	
Turn-Off Fall Time (Note 7)	t _F	_	-	30	ns		

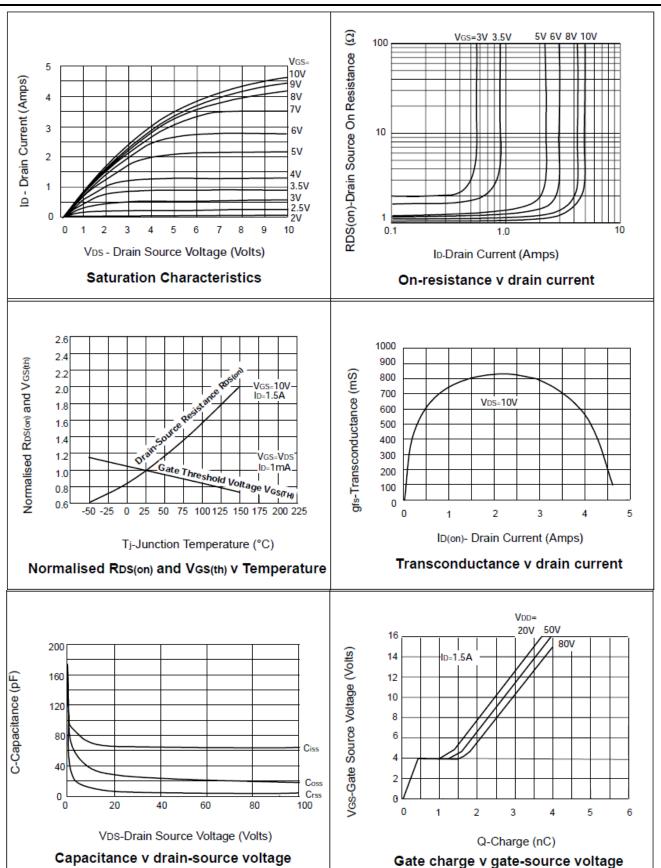
Notes:

- 5. Measured under pulsed conditions. Width=300 μ s. Duty cycle \leq 2%.

^{6.} Sample test.
7. Switching times measured with 50Ω source impedance and <5ns rise time on a pulse generator. Spice parameter data is available upon request for this



Electrical Characteristics

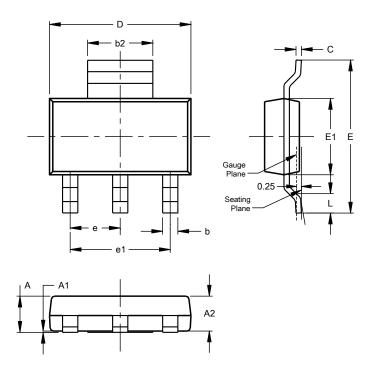




Package Outline Dimensions

Please see http://www.diodes.com/package-outlines.html for the latest version.

SOT223 (Type DN)

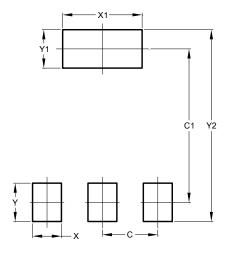


SOT223 (Type DN)				
Dim	Min	Max	Тур	
Α		1.70		
A1	0.01	0.15		
A2	1.50	1.68	1.60	
b	0.60	0.80	0.70	
b2	2.90	3.10		
С	0.20	0.32		
D	6.30	6.70		
Е	6.70	7.30		
E1	3.30	3.70		
е			2.30	
e1			4.60	
L	0.85			
All Dimensions in mm				

Suggested Pad Layout

Please see http://www.diodes.com/package-outlines.html for the latest version.

SOT223 (Type DN)



Dimensions	Value (in mm)		
С	2.30		
C1	6.40		
Х	1.20		
X1	3.30		
Y	1.60		
Y1	1.60		
Y2	8.00		



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